NSN 5961-00-168-1632



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-00-168-1632 **Inclosure Material:** Metal **Overall Length:** Between 0.195 inches and 0.215 inches Overall Diameter: Between 0.440 inches and 0.460 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.138 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 breakdown voltage, collector-to-emitter, base open and 5.0 collector to emitter voltage, dc and 1.2 base to emitter voltage, dc and 120.0 breakdown voltage, collector to emitter, sustained **Current Rating Per Characteristic:** 30.00 microamperes zero-gate-voltage source current peak **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 89954-930c567 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unc **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization: